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Nineteenth Annual Single-Event Effects Symposium

Experimental Characterization of SEE of CMOS 90 nm PLL for the Identification of Dominant Response Circuits

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April 13, 2010



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Topics

- Milli-Beam Overview and Features
- PLL Block Diagram and Layout
- Milli-Beam Raster Scan of PLL Design
- Correlate PLL Errors to Physical Layout
- PLL Modeling, Dynamics and Jitter
- Measurement of Loss of Lock and Transient Behaviour



Milli-Beam Overview and Features

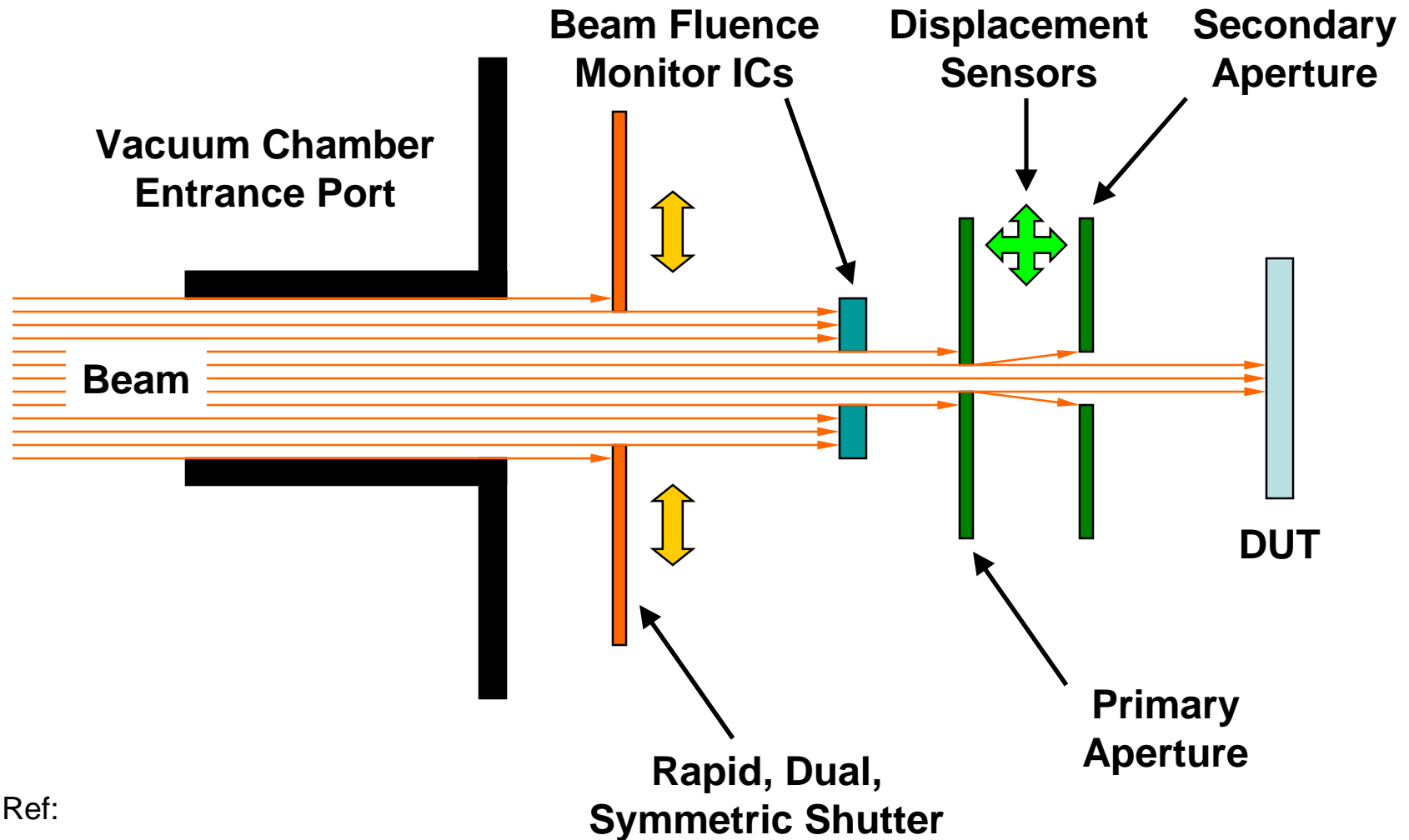
- **Precise beam collimation for use at the LBL cyclotron**
 - New hardware and software to raster scan complex ICs
 - Achieve spatial resolutions between 5 μm and 500 μm
- **Hardware**
 - Primary square aperture (2-orthogonal slits) stepped <1 μm precision
 - Secondary scattering cleanup aperture controlled from second stage
 - Displacement sensors provide error feedback signal for corrections
- **Software**
 - Computes coordinate transformations, sets beam position, controls run
 - Provides FPGA test board with positions for inclusion in error message
- **Independent ICs for beam characterization and dosimetry**
 - Homogeneous RAM for location and intensity profile measurement
 - Specially designed beam monitor ICs placed upstream of apertures
 - At preset fluences: block the beam, stop data acquisition, step apertures, update FPGA test board with new position, resume data acquisition, unblock the beam

Ref:

Dave Mavis, et. al. "New Test and Analysis Approaches for SEE Characterization," GOMACTech-10, 24 March 2010



Milli-Beam Schematic



Ref:

Dave Mavis, et. al. "New Test and Analysis Approaches for SEE Characterization," GOMACTech-10, 24 March 2010



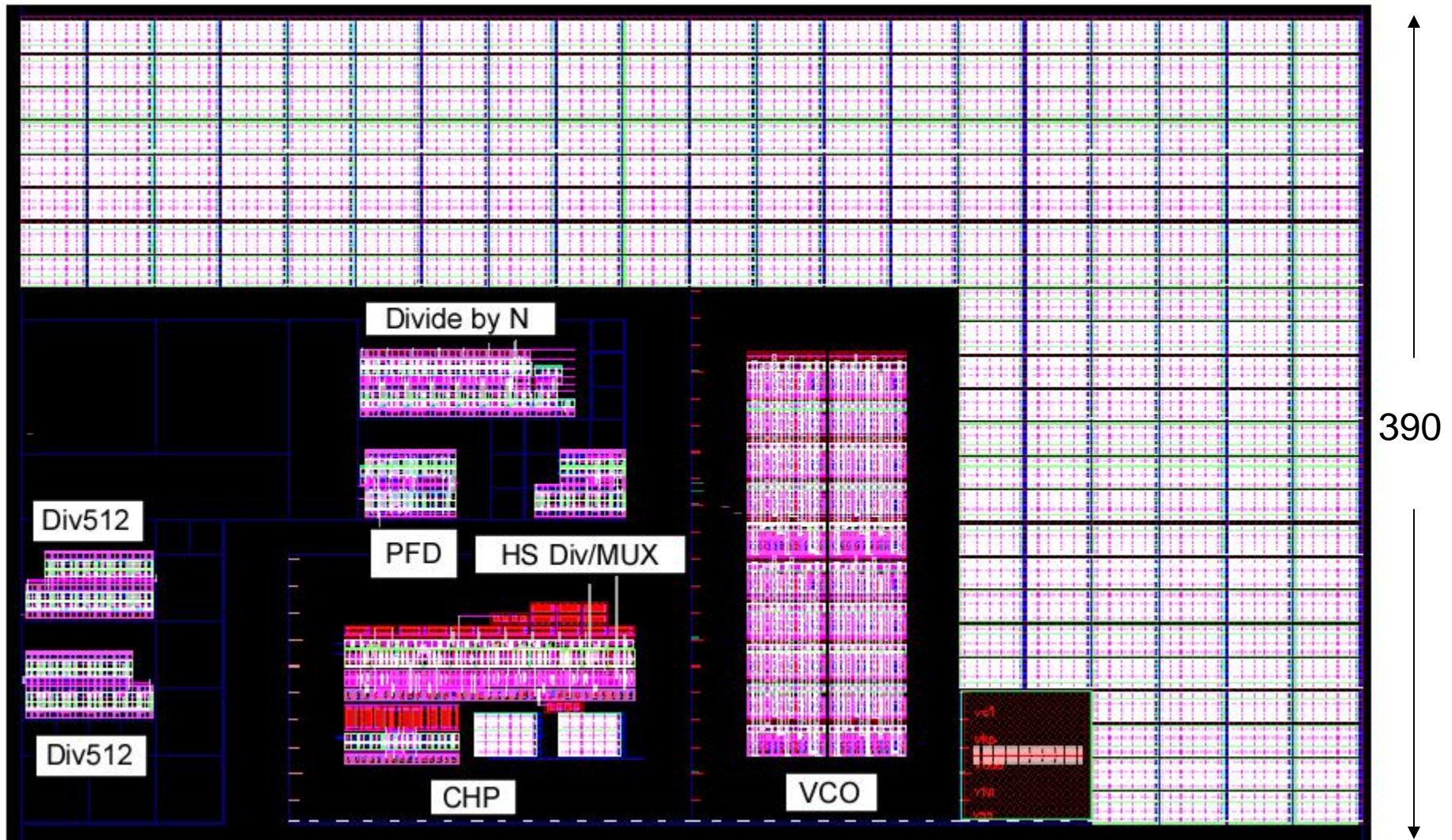
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Micro-RDC PLL Layout

IBM 90nm CMOS 9LP Process

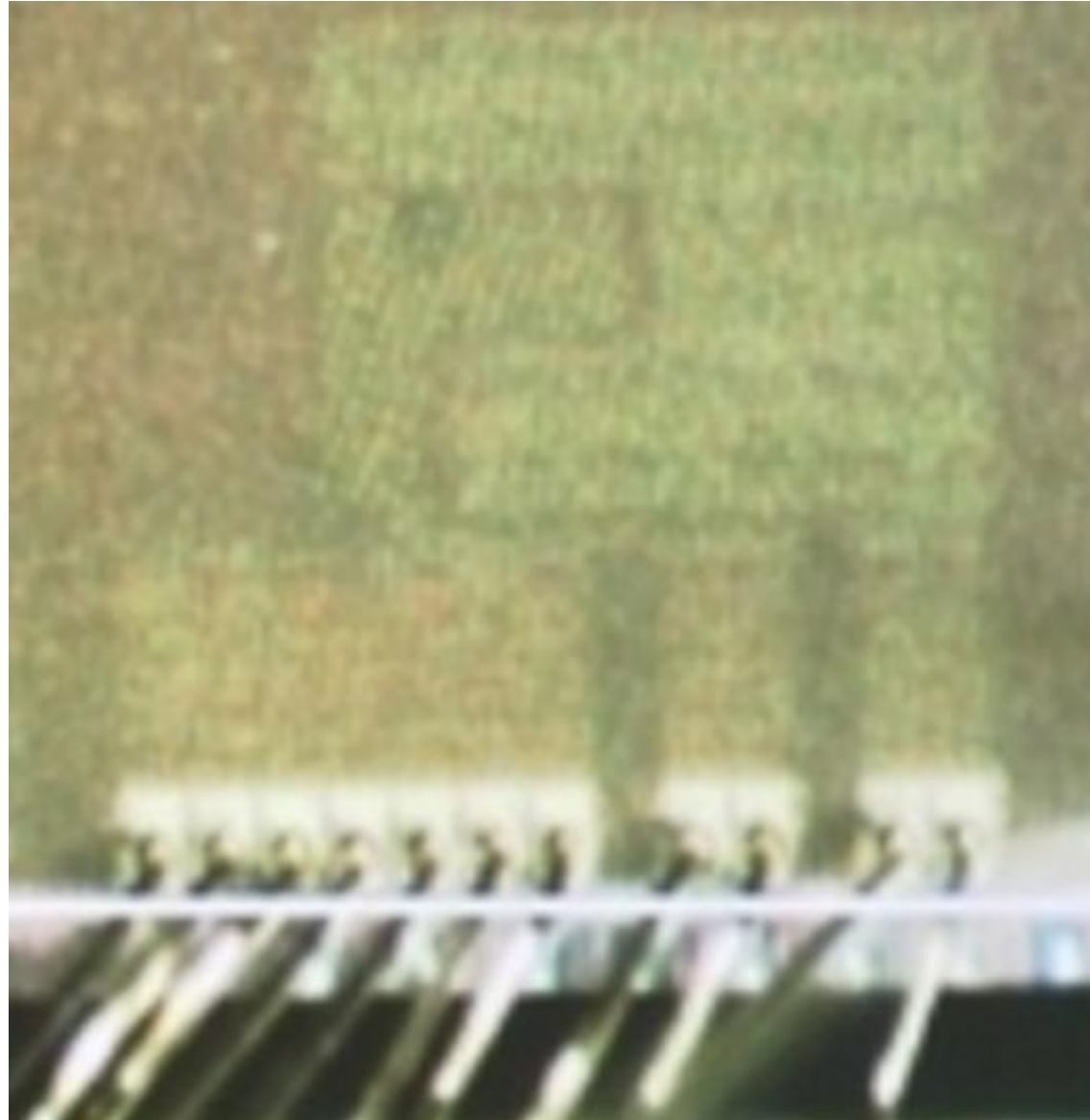
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Micro-RDC PLL Silicon Bonded Out

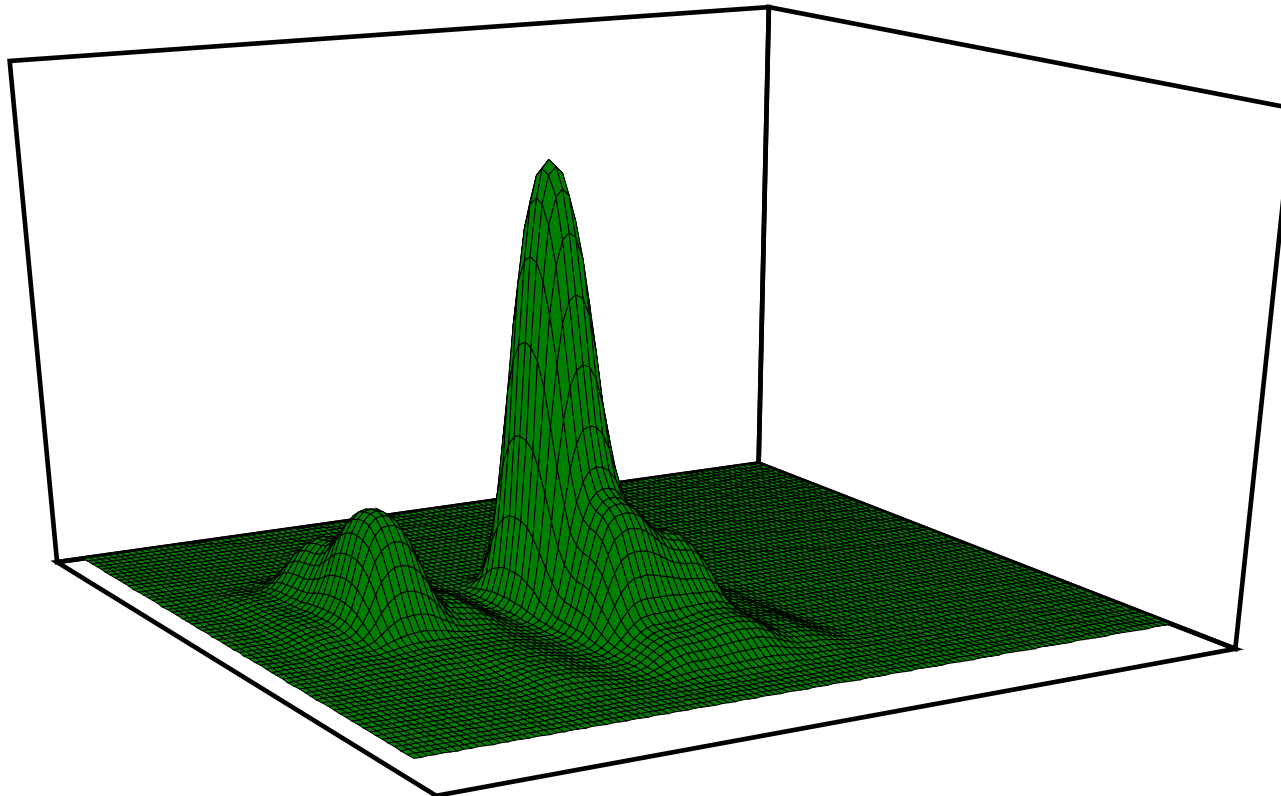


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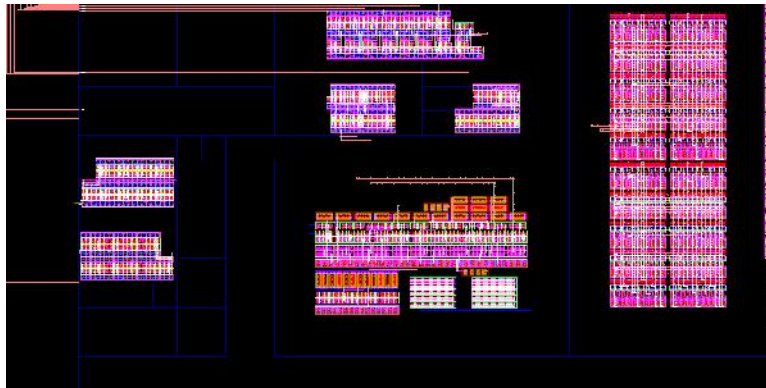
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Raster Scan of PLL Design

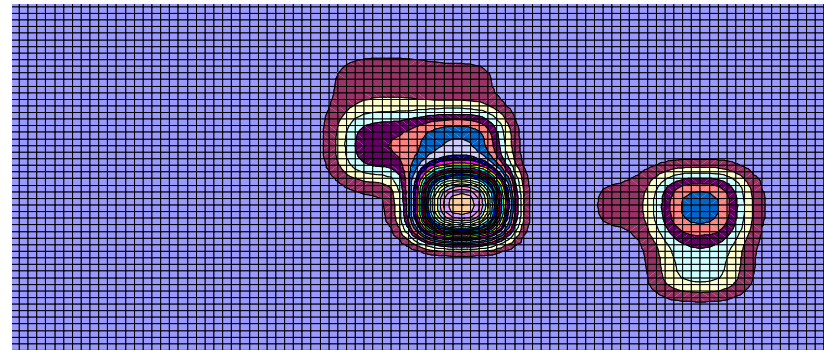
- **Scan a 100 μm square beam over the PLL circuitry**
 - Better approach than trying to test standalone circuit components
 - Monitor lock signal and measure recovery time
 - Correlate observed errors to specific circuits (CP, VCO, PSD, /N, \hat{M})



Correlate PLL Errors to Physical Layout



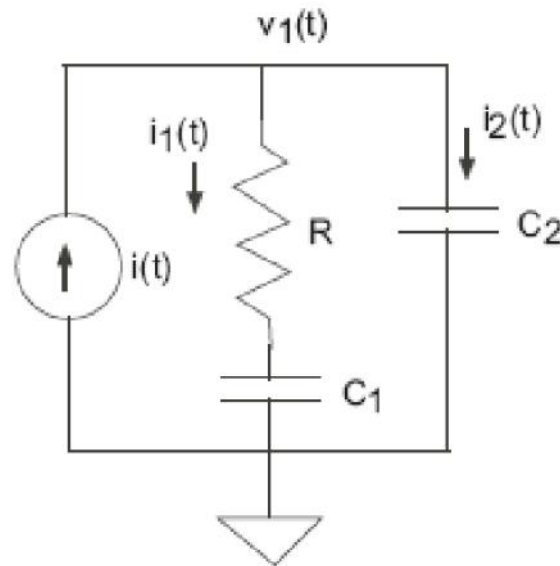
Design Layout



Milli-Beam Error Contours



Modeling the Charge Pump for High Level Simulation



Hanumolu, P.K.; Brownlee, M.; Mayaram, K.; Un-Ku Moon, “**Analysis of charge pump phase-locked loops**”, Circuits and Systems I: Regular Papers, *IEEE Transactions on Circuits and Systems I: Fundamental Theory and Applications*, Volume 51, Issue 9, Date: Sept. 2004, Pages: 1665 – 1674



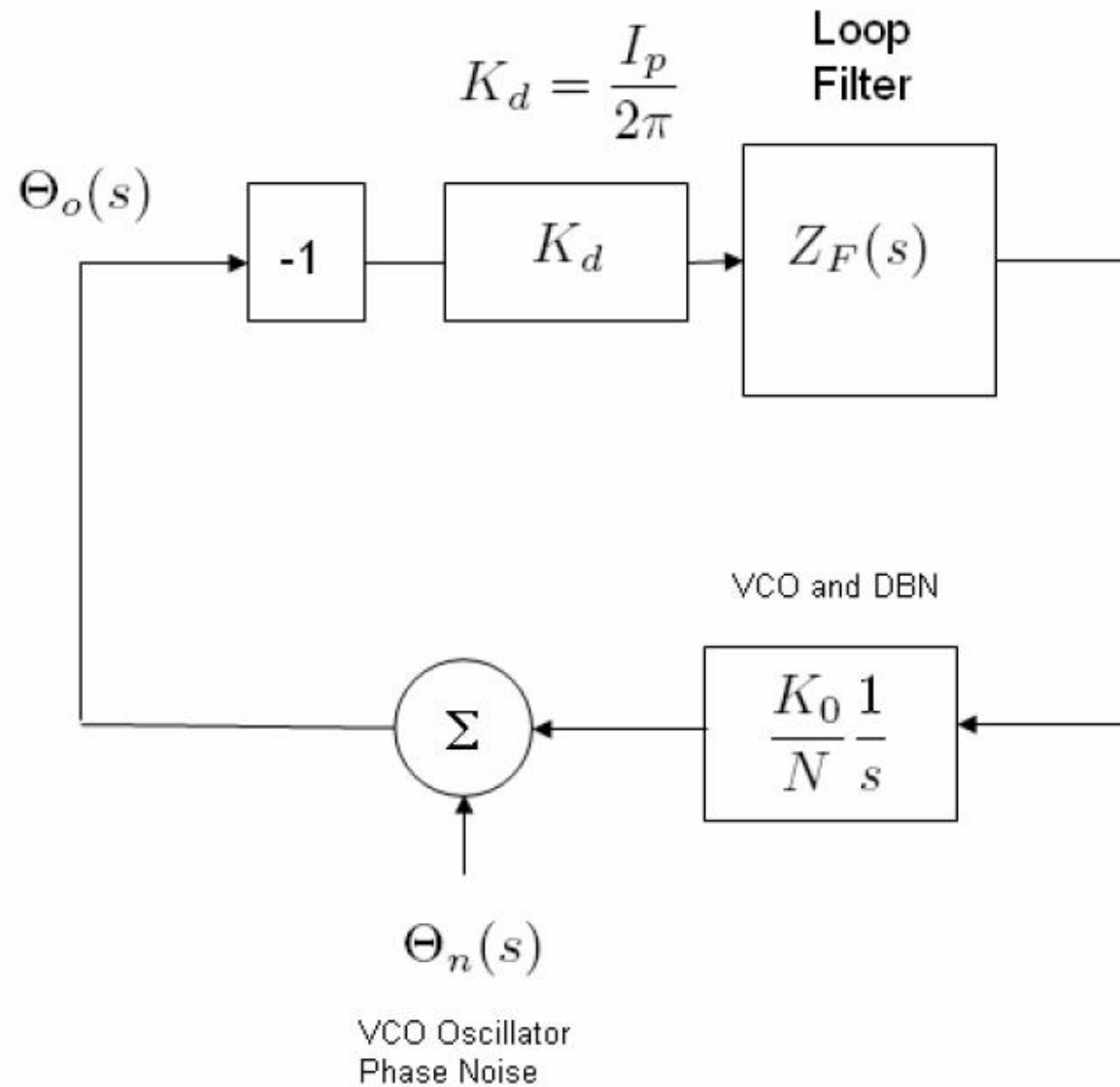
PLL Dynamics

The PLL bandwidth can be defined in terms of the loop gain

$$K = \frac{K_0 I_p R_1}{2\pi N}$$



PLL Jitter Analysis



PLL Jitter

The rms jitter in the synthesized clock

$$\sqrt{E[\Theta_{tot}^2(nT)]} = \sqrt{\frac{1}{2K_L T} \frac{2\pi \Delta\tau_{rms}}{T}}$$

$$K_L = \frac{K_0 I_p R_1}{2\pi N}$$

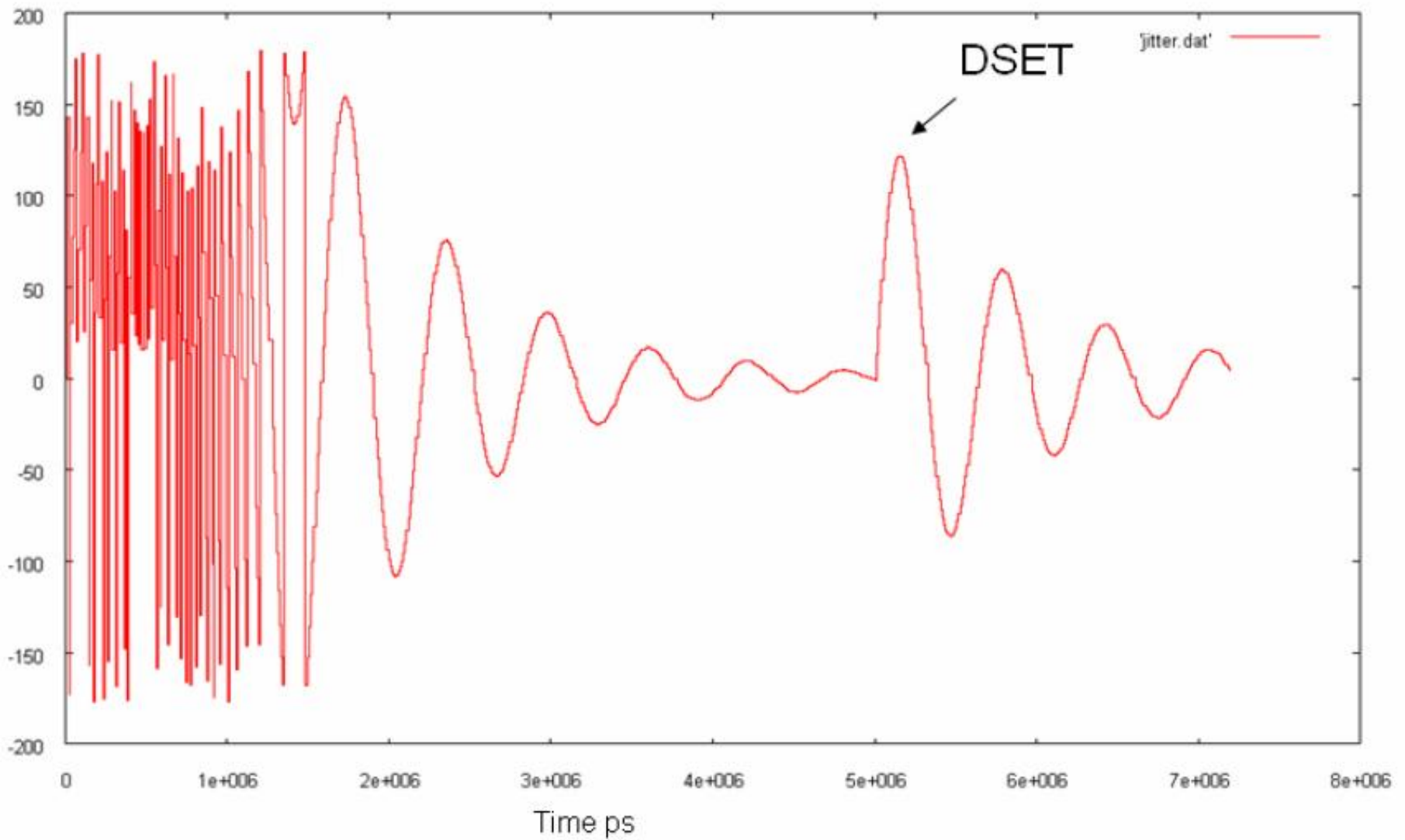
T Reference Clock Period.

The VCO jitter due to VCO phase noise $\Delta\tau_{rms}$

Beomsup Kim; Weigandt, T.C.; Gray, P.R. , **PLL/DLL system noise analysis for low jitter clock synthesizer design**, *IEEE International Symposium on Circuits and Systems*, 1994. ISCAS '94., 1994 Volume 4, Date: 30 May-2 Jun 1994, Pages: 31 - 34 vol.4



Jitter Performance with DSET



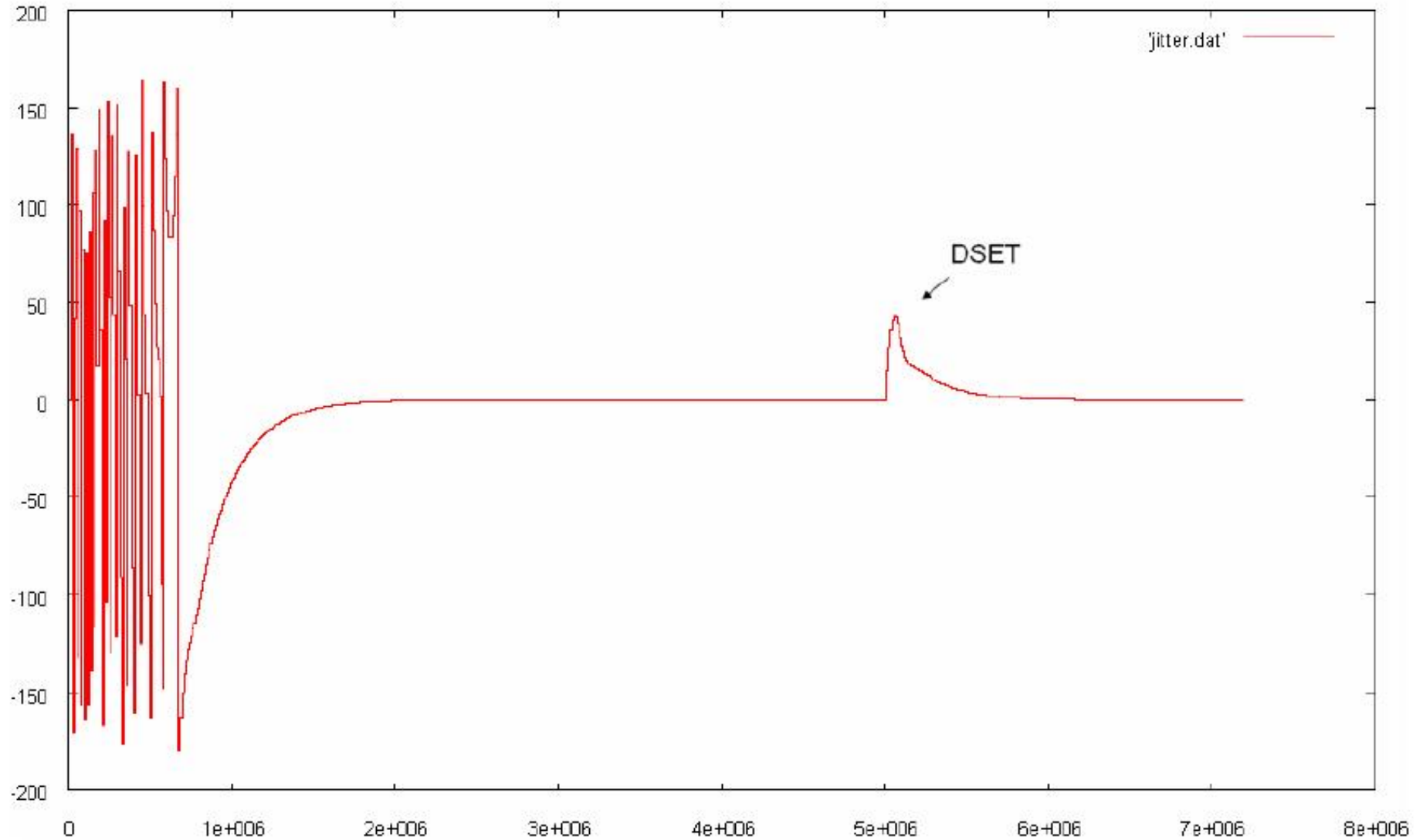
Jitter C1=50pF C2=5pF R=0.5k Ω



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Jitter Performance with DSET High Bandwidth



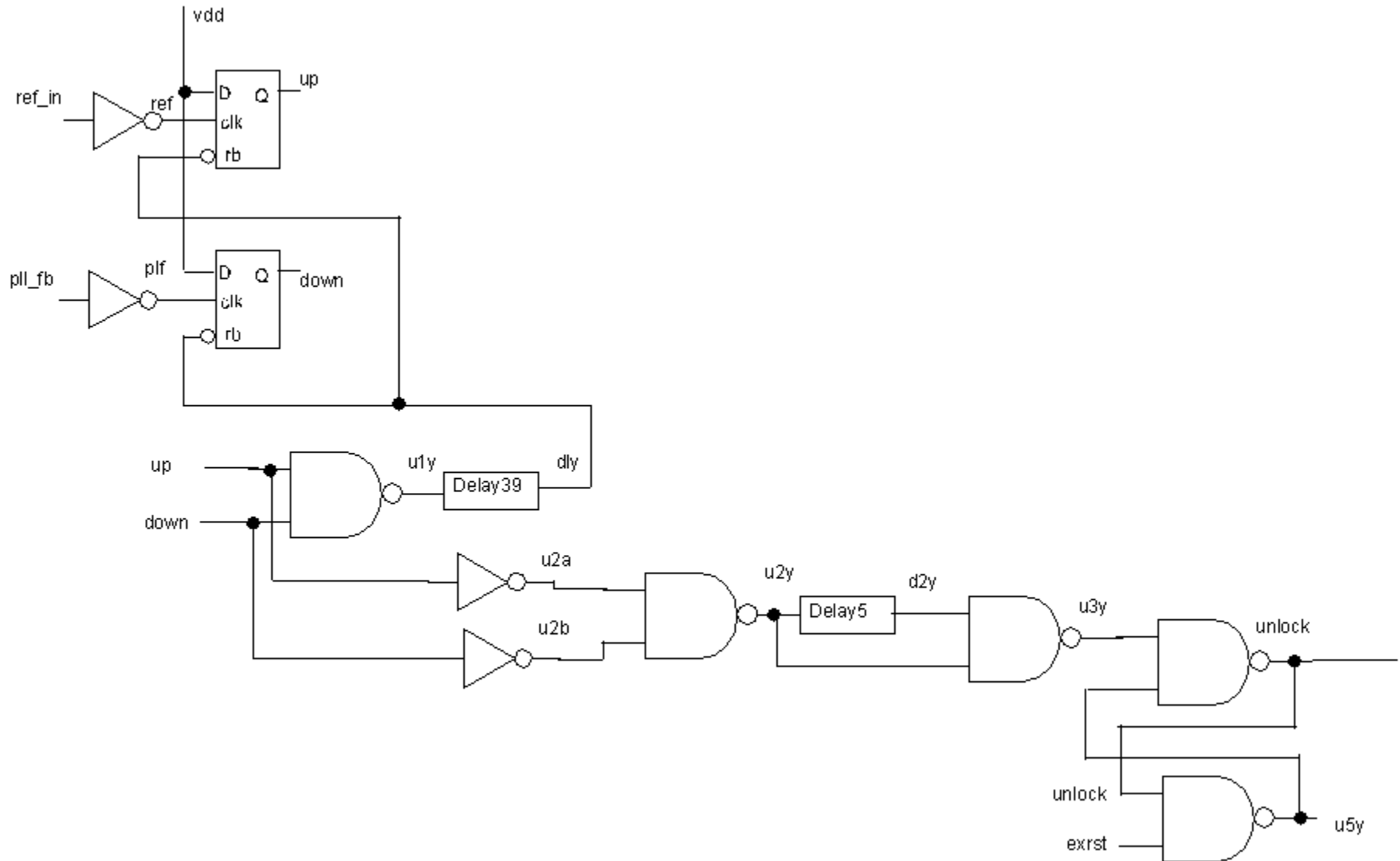
Jitter $C1=50\text{pF}$ $C2=5\text{pF}$ $R=5\text{k}\Omega$



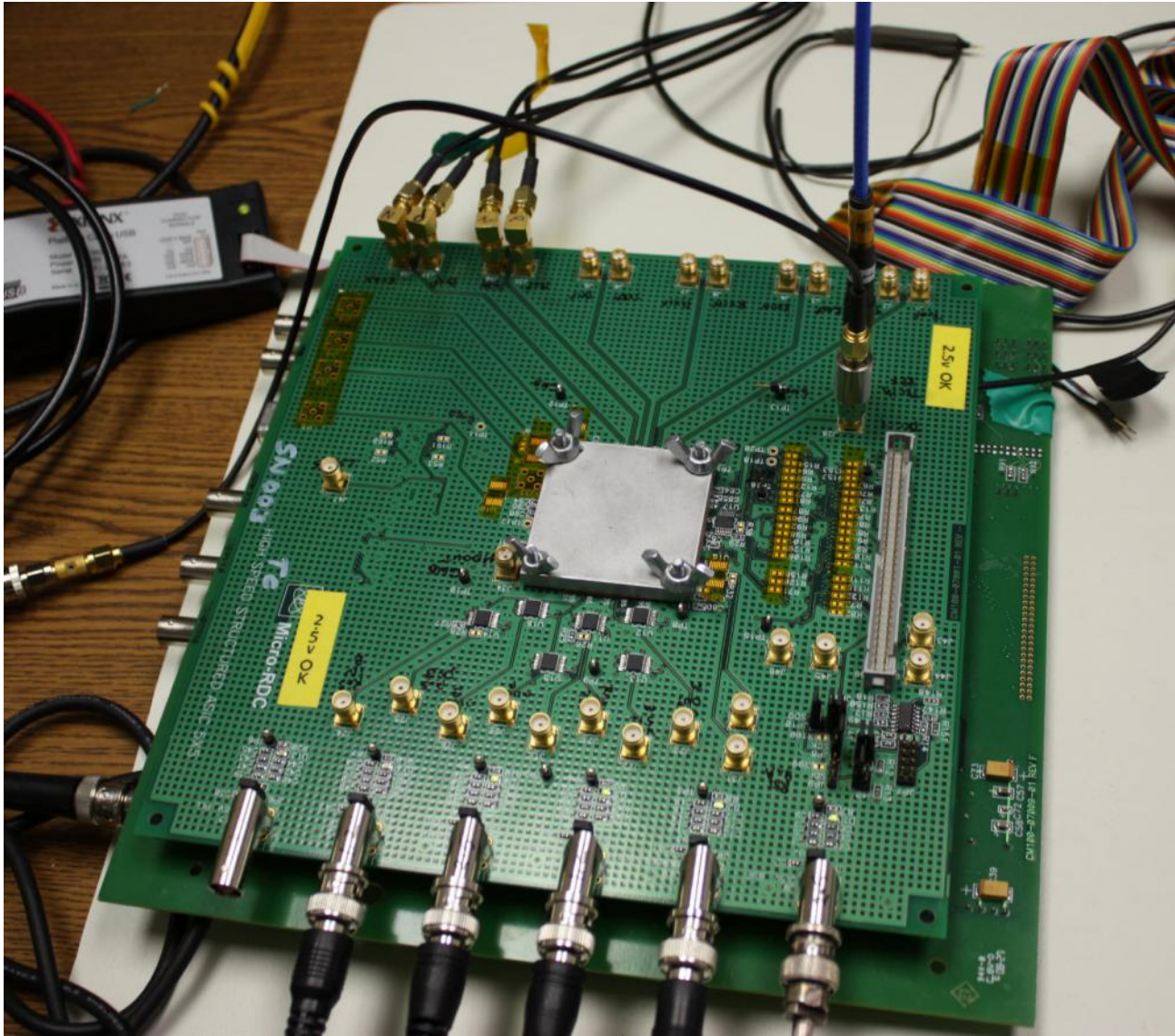
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Lock Detection with Transparent Mode



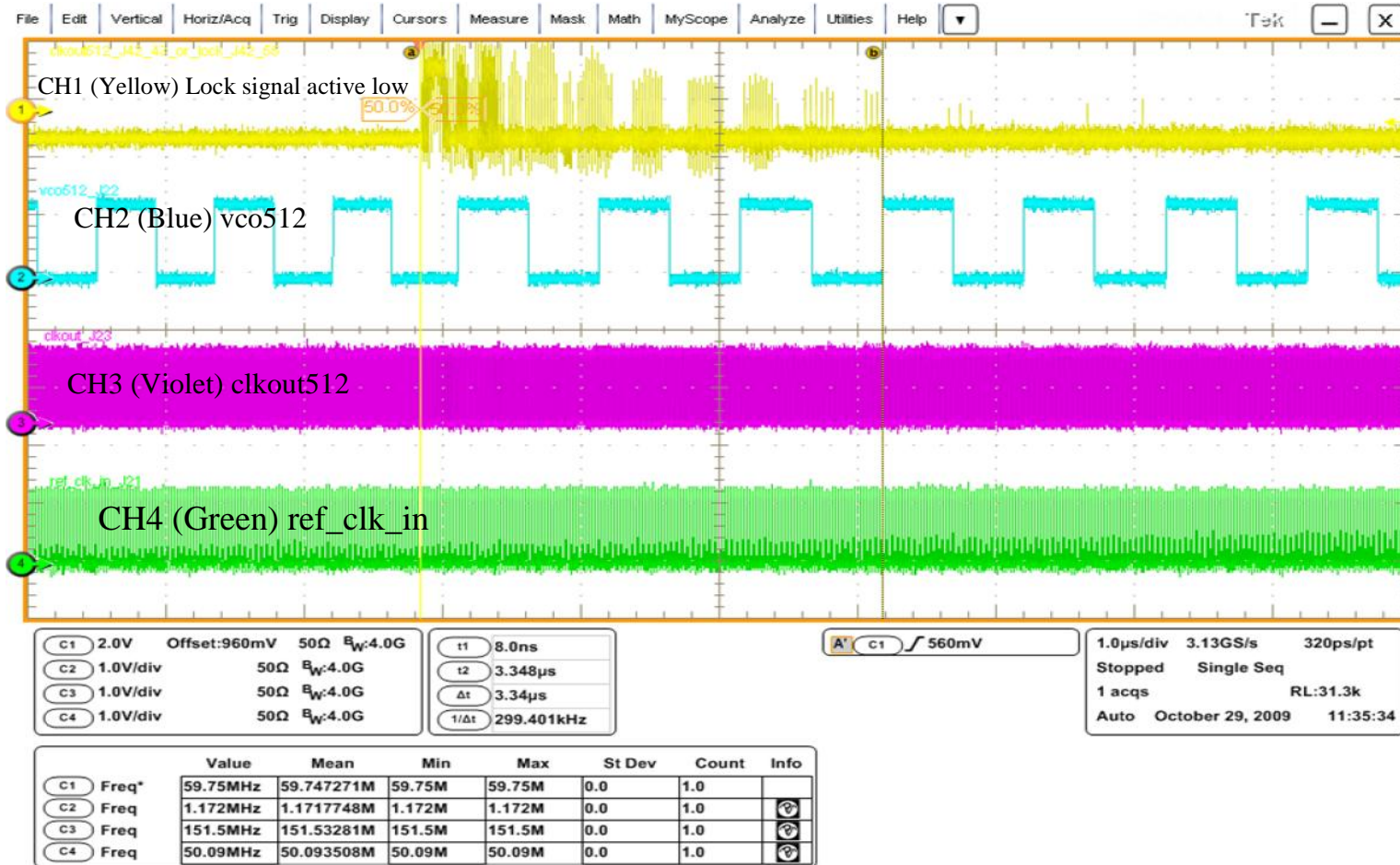
High Speed Daughter Card



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Scope Screen Capture of the Outputs of 90nm PLL During a Lock Recovery after Switching LD0 High to Low at 50MHz.



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Scope Screen Capture of the Outputs During a Lock Condition at 50MHz

